

# DATA SHEET

# SILICON TRANSISTOR ARRAY $\mu$ PA1428A

# NPN SILICON POWER TRANSISTOR ARRAY HIGH SPEED SWITCHING USE (DARLINGTON TRANSISTOR) INDUSTRIAL USE

### DESCRIPTION

The  $\mu$ PA1428A is NPN silicon epitaxial Darlington Power Transistor Array that built in Surge Absorber 4 circuits designed for driving solenoid, relay, lamp and so on.

### **FEATURES**

- Surge Absorber built in.
- Easy mount by 0.1 inch of terminal interval.
- High hre for Darlington Transistor.

### ORDERING INFORMATION

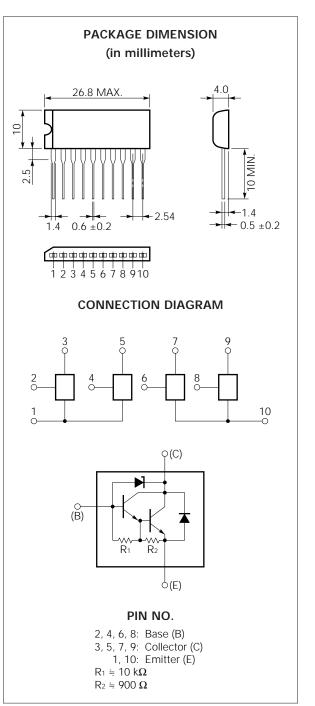
Part Number	Package	Quality Grade	
μΡΑ1428AH	10 Pin SIP	Standard	

Please refer to "Quality grade on NEC Semiconductor Device" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Collector to Base Voltage	Исво	60 ±10	V				
Collector to Emitter Voltage	Vceo	60 ±10	V				
Emitter to Base Voltage	Vebo	8	V				
Surge Sustaining Energy	Eceo(sus)	30	mJ/unit				
Collector Current (DC)	IC(DC)	±2	A/unit				
Collector Current (pulse)	C(pulse)*	±3	A/unit				
Base Current (DC)	B(DC)	0.2	A/unit				
Total Power Dissipation	PT1**	3.5	W				
Total Power Dissipation	PT2***	28	W				
Junction Temperature	Tj	150	°C				
Storage Temperature	Tstg -5	5 to +15	50 °C				
* PW $\leq$ 350 $\mu$ s, Duty Cycle $\leq$ 2 %							
** 4 Circuits, Ta = 25 °C							

\*\*\* 4 Cuircuits, Tc = 25 °C



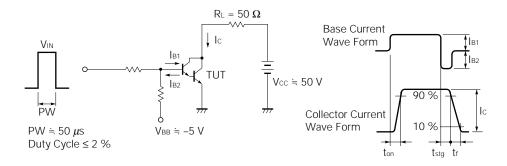
The information in this document is subject to change without notice.

# ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

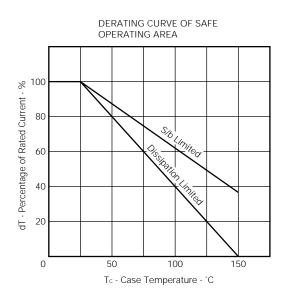
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Collector Leakage Current	Ісво			1	μA	$V_{CB} = 40 V, I_{E} = 0$	
Emitter Leakage Current	Ево			5	mA	$V_{EB} = 5 V, Ic = 0$	
Collector to Emitter Sustaining Voltage	VCEO(sus)	50	60	70	V	Ic = 1 A, L = 1 mH	
DC Current Gain	hfei *	2000		20000	_	Vce = 2 V, Ic = 1 A	
DC Current Gain	hfe2 *	500			—	$V_{CE} = 2 V$ , $I_C = 2 A$	
Collector Saturation Voltage	VCE(sat) *		1.0	1.5	V	Ic = 1 A, IB = 1 mA	
Base Saturation Voltage	VBE(sat) *		1.7	2	V	Ic = 1 A, I <sub>B</sub> = 1 mA	
Turn On Time	ton		0.4		μs	$ \begin{array}{l} I_{C} = 1 \ A \\ I_{B1} = -I_{B2} = 2 \ mA \\ V_{CC} \doteq 50 \ V, \ R_{L} = 50 \ \Omega \\ See \ test \ circuit \end{array} $	
Storage Time	tstg		1.5		μs		
Fall Time	tr		0.4		μs		

\* PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2 %/pulsed

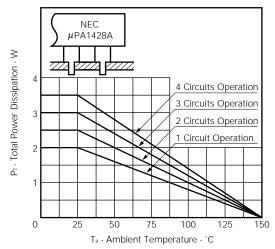
# SWITCHING TIME TEST CIRCUIT



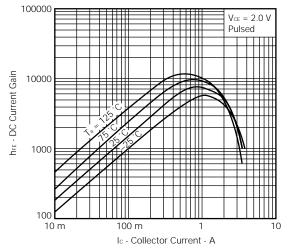
TYPICAL CHARACTERISTICS (Ta = 25 °C)

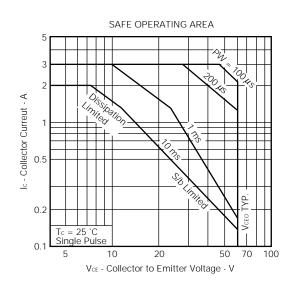


TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

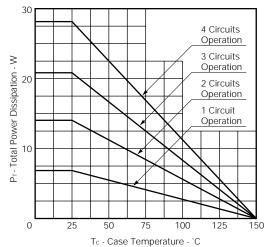




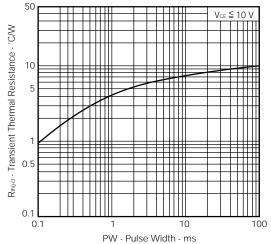


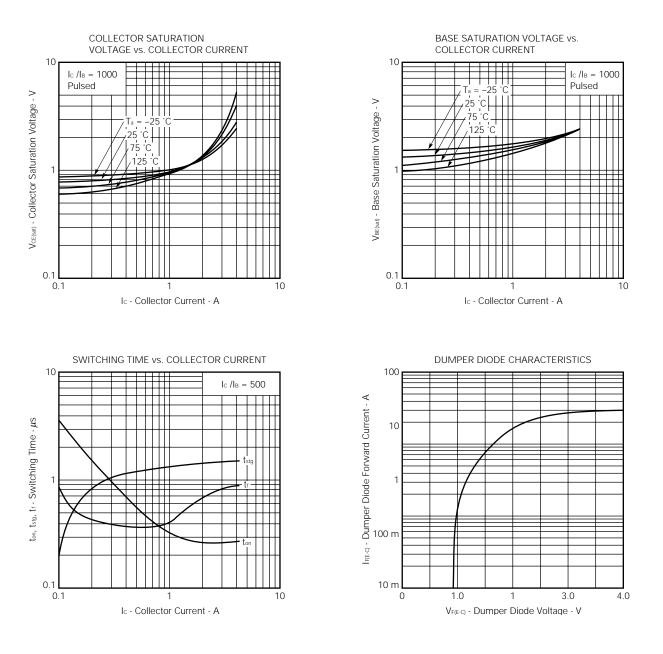


TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



TRANSIENT THERMAL RESISTANCE





## REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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